



IXFN30N110P Information



For Reference Only

Part Number IXFN30N110P

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1100V 25A SOT-227B

Package SOT-227-4, miniBLOC

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXFN30N110P Specifications

Manufacturer Part Number	IXFN30N110P
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-227-4, miniBLOC
Series	Polar?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1100V
Current - Continuous Drain (Id) @ 25°C	25A
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	6.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	235nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	13600pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	695W (Tc)
Rds On (Max) @ Id, Vgs	360 mOhm @ 15A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Supplier Device Package	SOT-227B
Package / Case	SOT-227-4, miniBLOC
	Report errors?

IXFN30N110P Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFN30N110P Payment Methods





















IXFN30N110P Shipping Methods













If you have any question about IXFN30N110P, please do not hesitate to contact us!

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